

Synthesis of Inorganic Solids

Classification

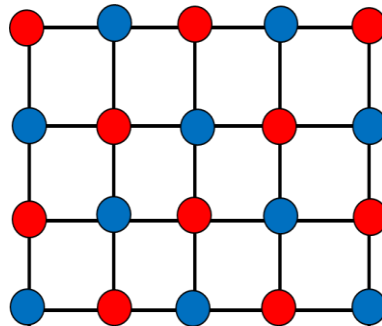
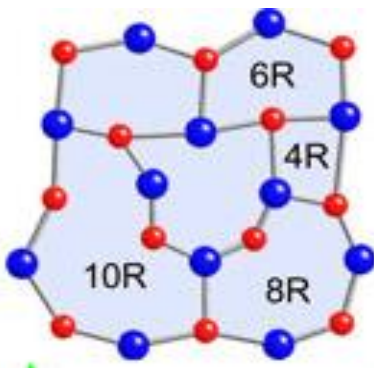
Inorganic Solids

Amorphous

Irregular arrangement of atoms
Non periodic, disorder structure



Natural amorphous
Solution processed (RT or low temp)
Quenching from melts



Crystalline

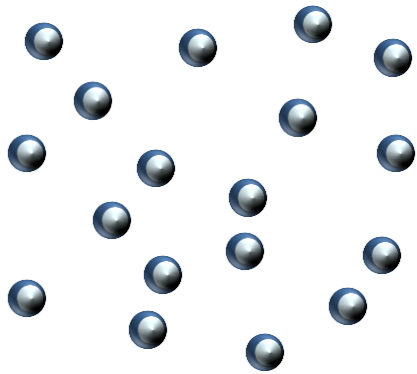
regular arrangement of atoms
periodic, highly order structure



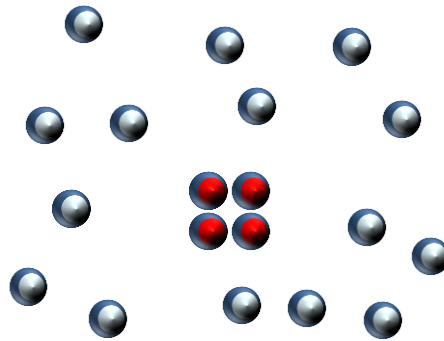
Solid state synthesis
Flux techniques (salt or metals)
Chemical vapor transport
Solution combustion
Hydro/solvothermal synthesis
Bridgman crystal growth
Czochralski process

Crystal Growth

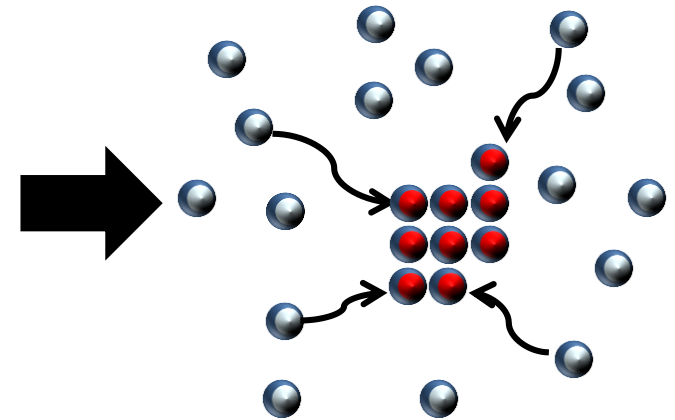
Mobile atoms



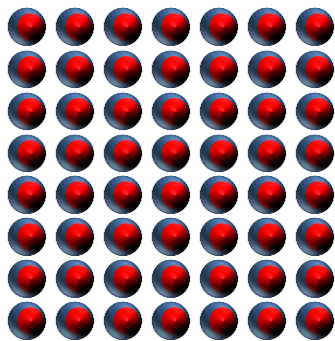
Nucleation



Growth

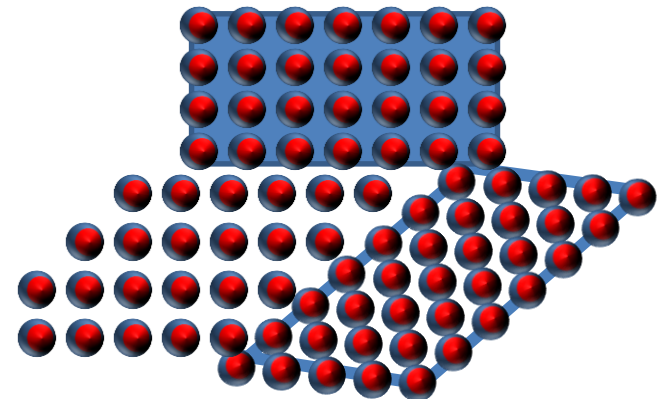


Single crystal



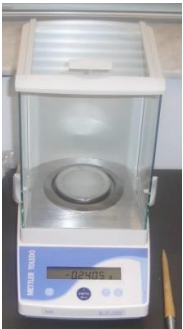
vs.

polycrystalline



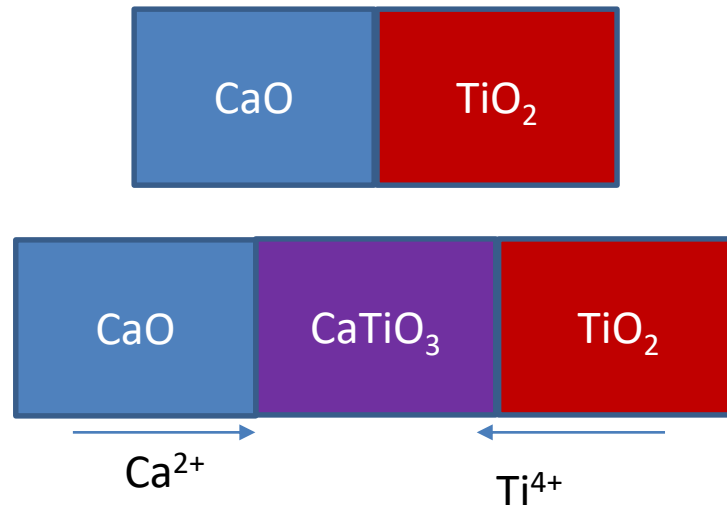
Solid state synthesis

- Reaction among the ions of the solids
- The most useful method for the synthesis of inorganic solids, oxides, nitrides, phosphates, silicates, chalcogenides, etc.
- Reaction: $\text{CaO} + \text{TiO}_2 = \text{CaTiO}_3$ ($\geq 1300^\circ\text{C}$)
 - # Homogeneous mixture of the solids
 - # Pressed into pellets



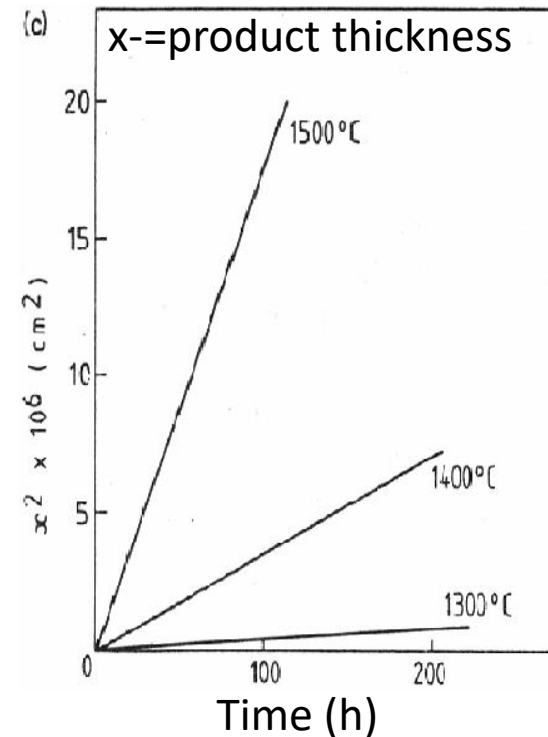
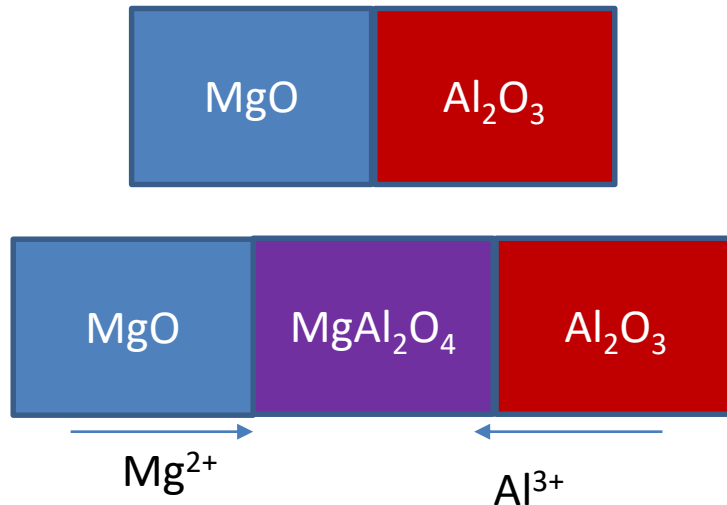
Mechanism of Solid State Reaction

Reaction mechanism: $\text{CaO} + \text{TiO}_2 = \text{CaTiO}_3$



- # Reaction only occurs at the contact of the grains of CaO and TiO₂
- # Get nucleation at the contact point and then get diffuses to grow products
- # Diffusion control
- # Require high Temperature ($\geq 500^\circ\text{C}$), use absolute temperature that is $> 2/3$ of the MP of lowest melting reactant
- # Often leads to inhomogeneity
- # Reaction is very slow

Mechanism of Solid State Reaction



Interdiffusion of cations to form single crystals of MgO and Al_2O_3 , Thickness, x of MgAl_2O_4 product layer as a function of temperature and time. (Pettit, Randklevand Felton, 1966)

The Phase Rule

- The phase rule; Gibbs phase rule (1875), relates the number of components and the number of degrees of freedom in a system at equilibrium by the formula

$$F = C - P + 2 \quad \text{or} \quad F + P = C + 2$$

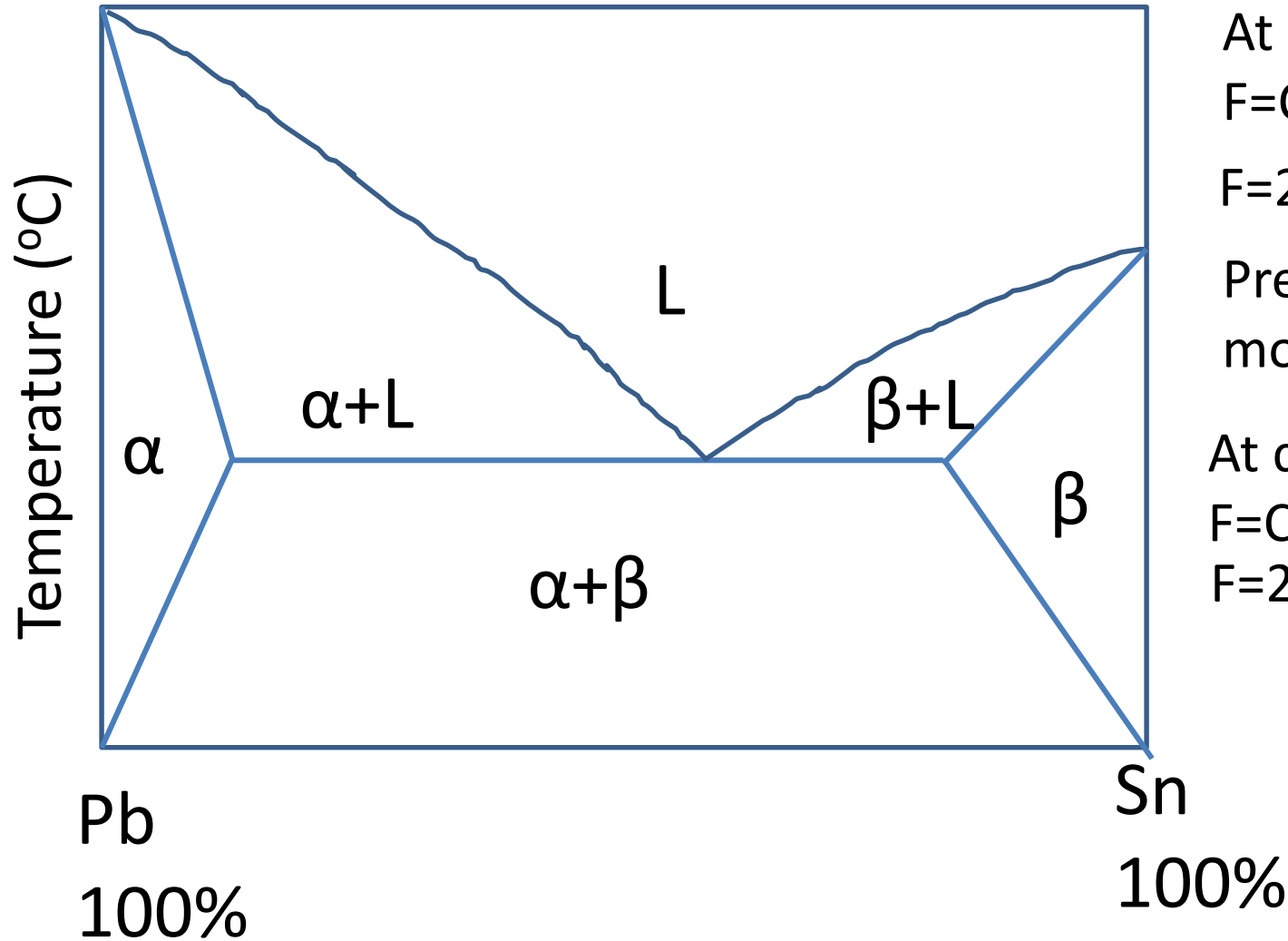
F equals the number of degrees of freedom or the number of independent variables

C equals the number of components in a system in equilibrium

P equals the number of phases

The digit 2 stands for the two variables, temperature and pressure

Phase Rule



At α

$$F = C - P + 2$$

$$F = 2 - 1 + 2 = 3$$

Pressure, Temp,
mole fraction

At $\alpha + \beta$

$$F = C - P + 2$$

$$F = 2 - 2 + 2 = 2$$

At constant pressure

The Lever rule

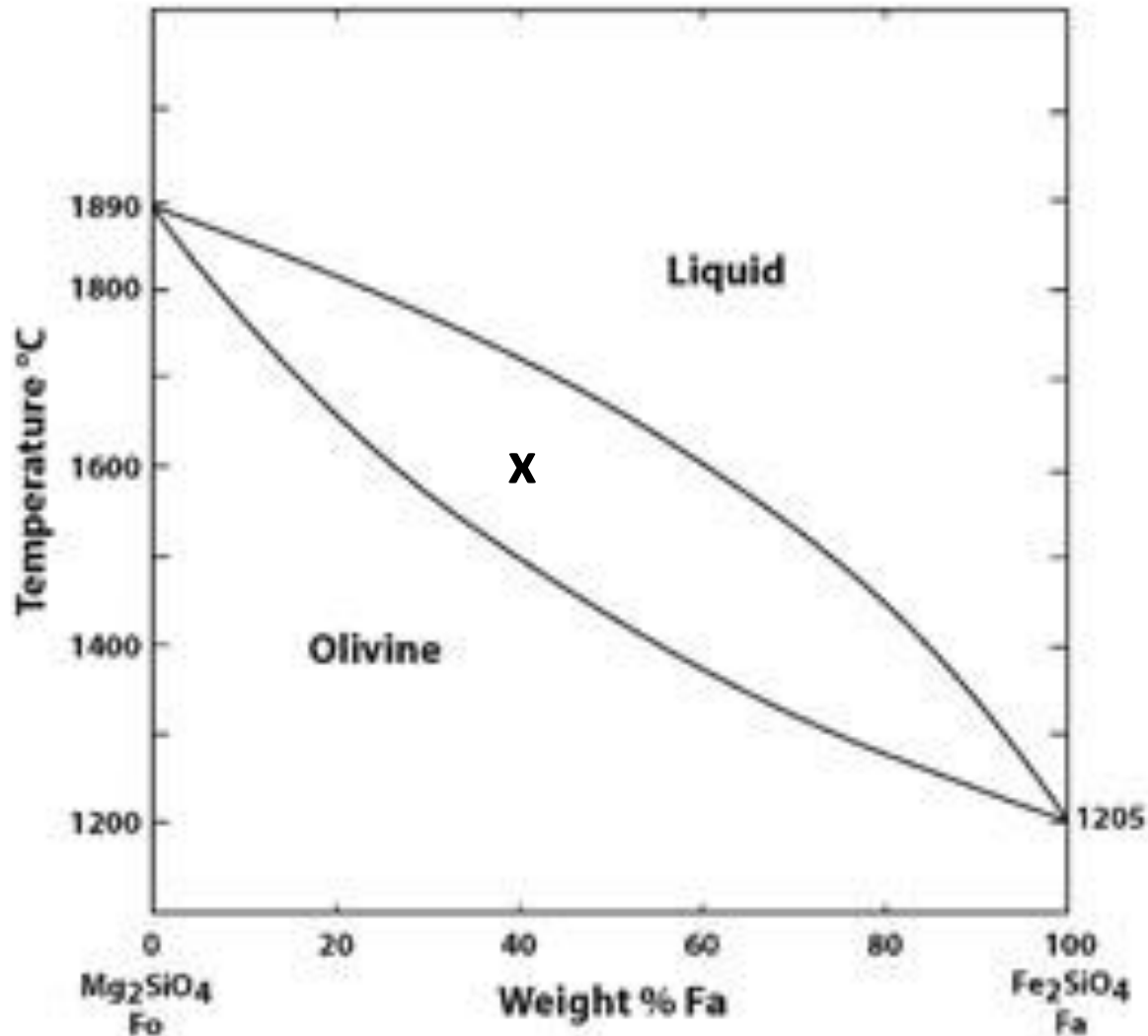
Finding the amounts of phases in a two phase region:

Step 1: Locate composition and temperature in diagram

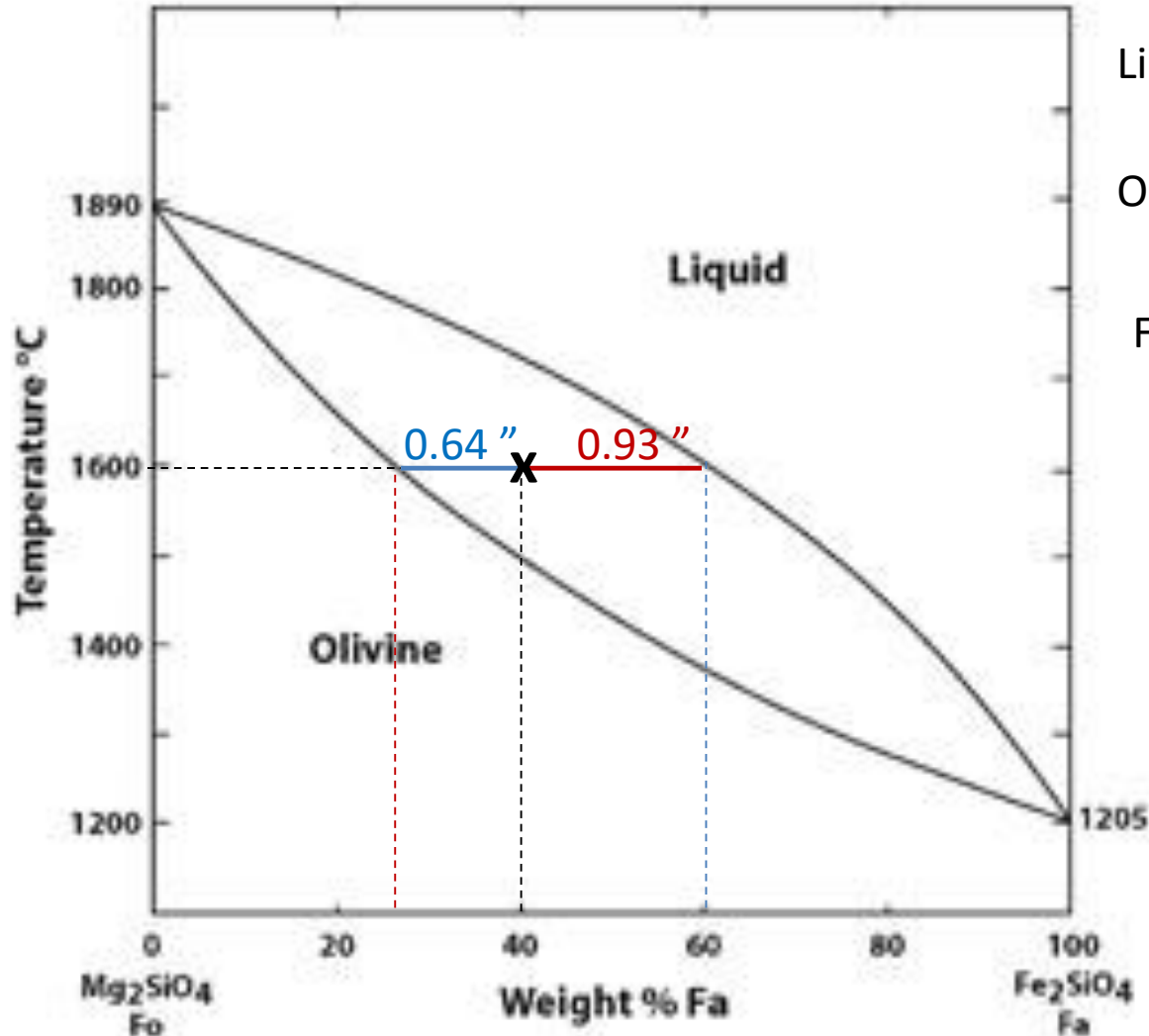
Step 2: In two phase region draw the tie line or isotherm

Step 3: Fraction of a phase is determined by taking the length of the tie line to the phase boundary **for the other phase** and dividing by the total length of tie line.

2-Component System



2-Component System



Liquid Composition = 60% Fe_2SiO_4

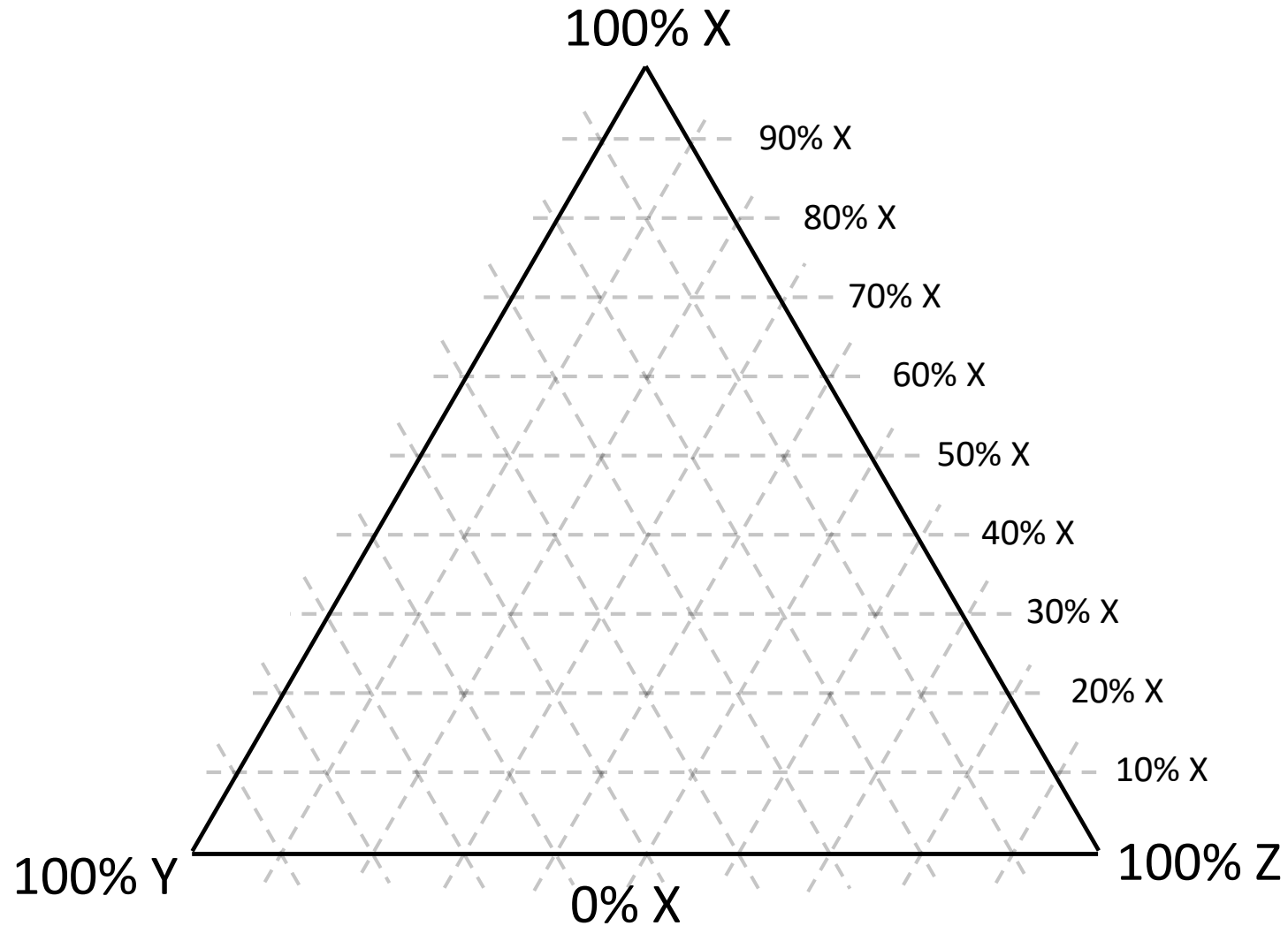
Olivine Composition = 27% Fe_2SiO_4

$$\text{Fraction Olivine} = \frac{0.93}{0.64 + 0.93} = 0.59$$

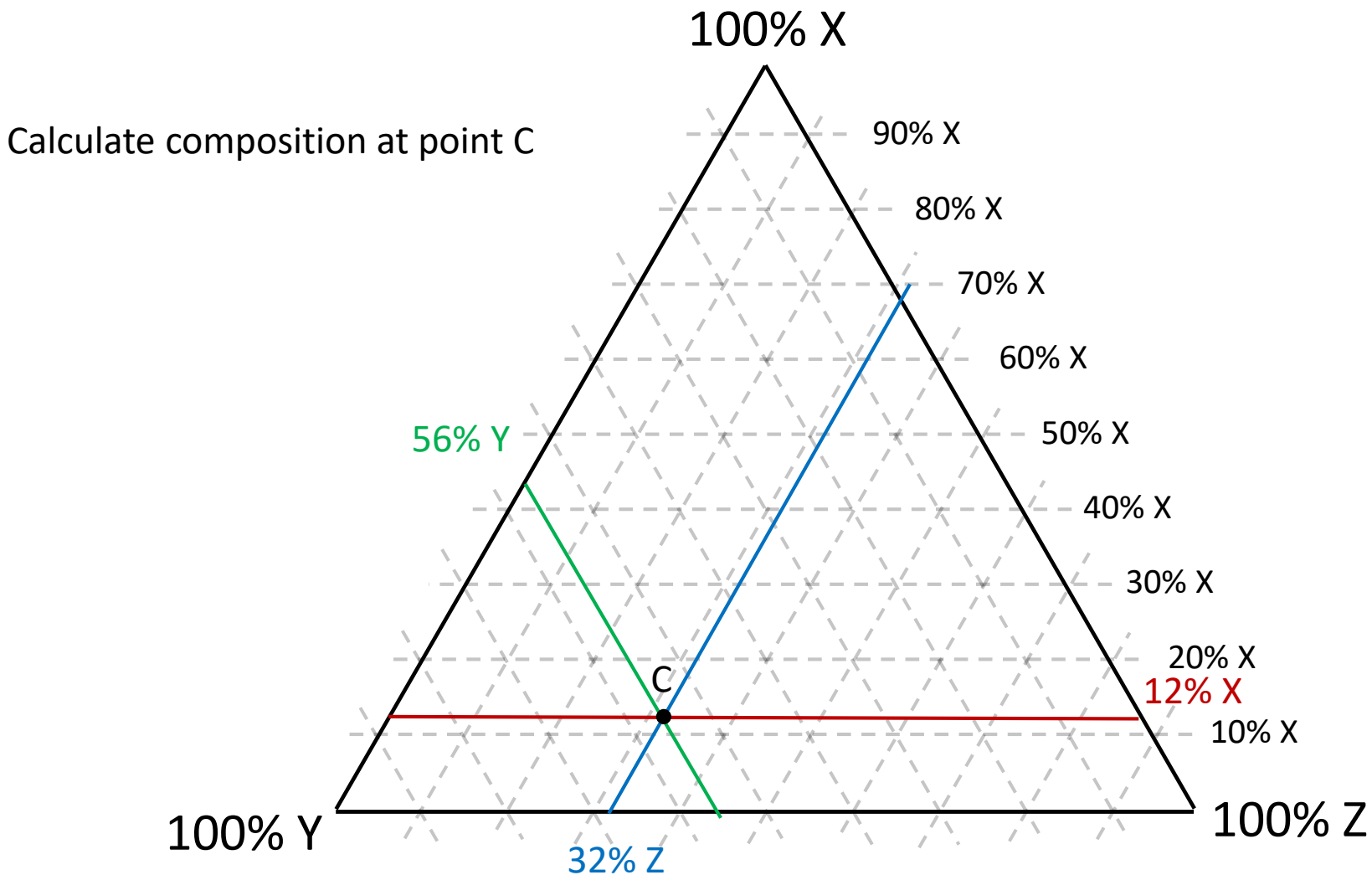
Fraction Liquid = 0.41

Calculate fraction olivine, liquid composition, and olivine composition at a global composition of 70% Fe_2SiO_4 at 1450 $^{\circ}\text{C}$

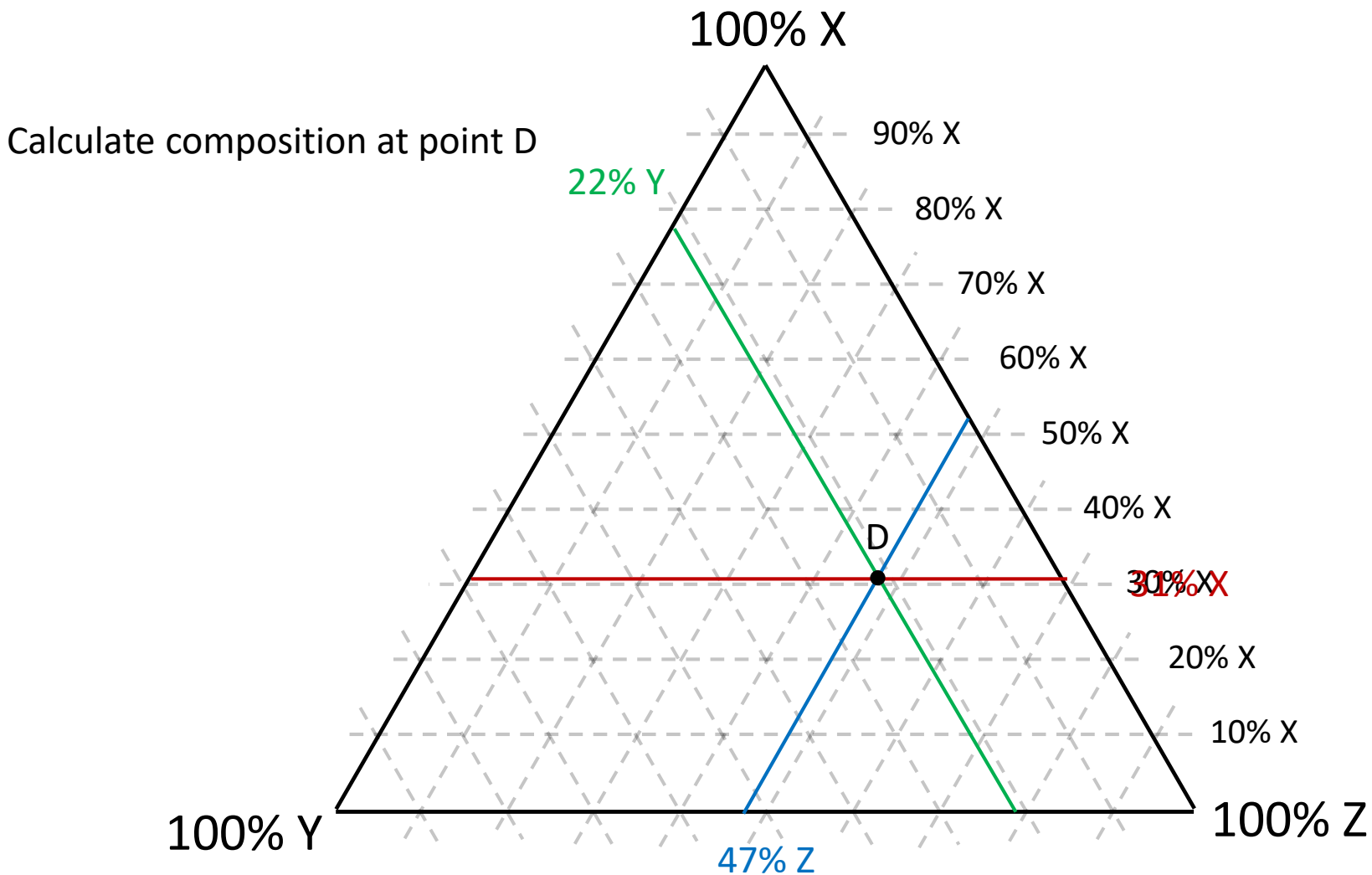
3-Component Systems



Calculating Compositions



Calculating Compositions



Exploring the Y-Ba-Cu System

- Each pair of students will synthesize the $\text{YBa}_2\text{Cu}_3\text{O}_{7-\delta}$ (YBCO) superconducting phase
- You will analyze the products formed via PXRD
- Each pair of students will calculate masses of reagents needed for one additional point on the phase diagram.
- You will draw the phase diagram based on phases we provide you

Y – Ba – Cu

Consider the ratios of Y, Ba, and Cu in $\text{YBa}_2\text{Cu}_3\text{O}_{7-\delta}$ (YBCO).

1. Calculate the mole fraction of each metal in YBCO.
2. Plot the point on the diagram corresponding to YBCO.
3. Calculate masses of each reagent needed to form 2 grams of YBCO.

Molar Masses

Y_2O_3 – 225.81 g/mol

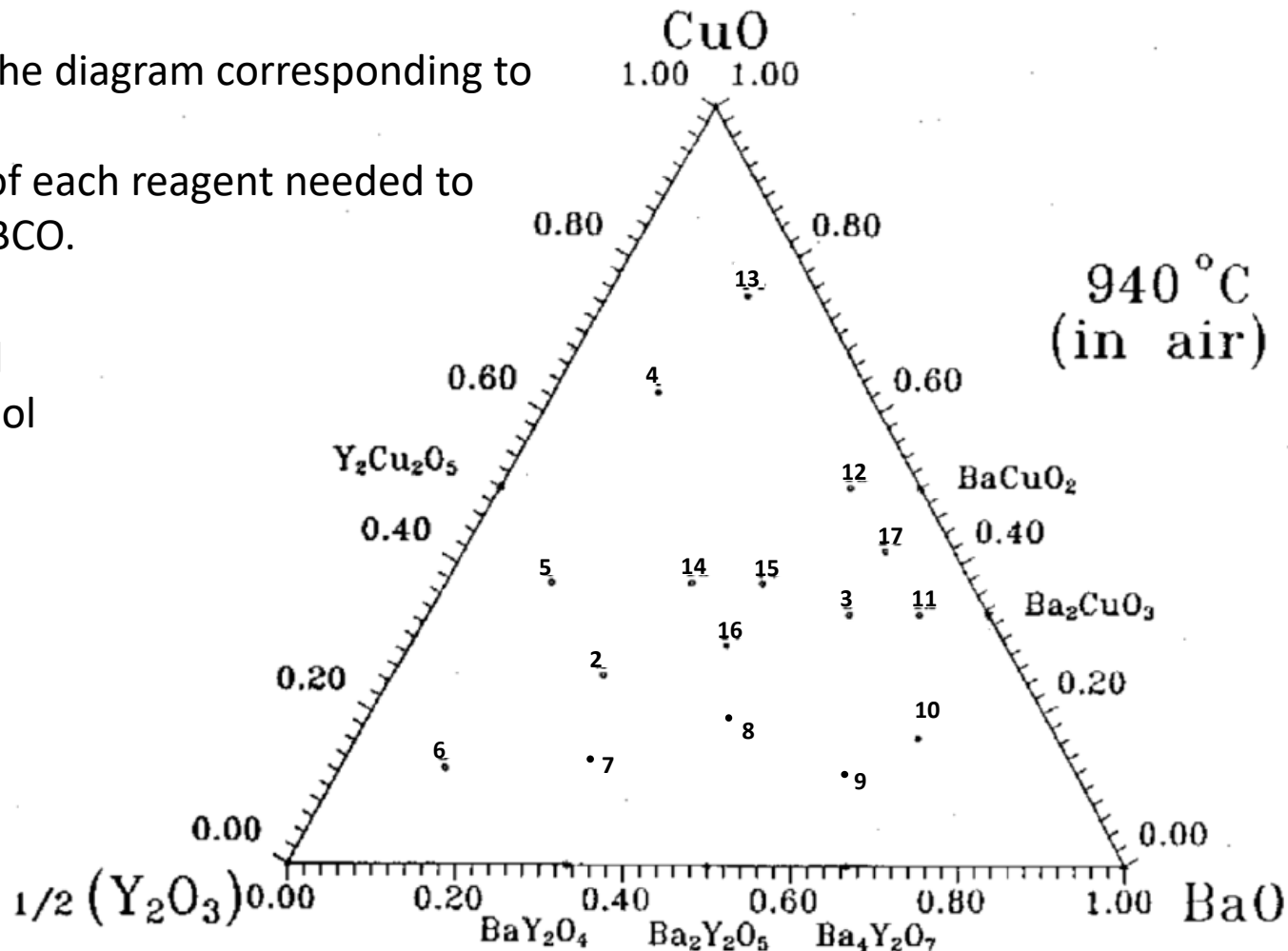
BaCO_3 – 197.34 g/mol

CuO – 79.545 g/mol

Y – 88.91 g/mol

Ba – 137.33 g/mol

Cu – 63.55 g/mol



Y – Ba – Cu

4. Choose one other point on the phase diagram and calculate masses of each reagent needed for 2 grams of total product.

You can predict the amount of oxygen in the final product based on the metal oxidation states. For example, a 1 : 1 : 1 ratio would have a hypothetical formula of $\text{YBaCuO}_{3.5}$.

Molar Masses

Y_2O_3 – 225.81 g/mol

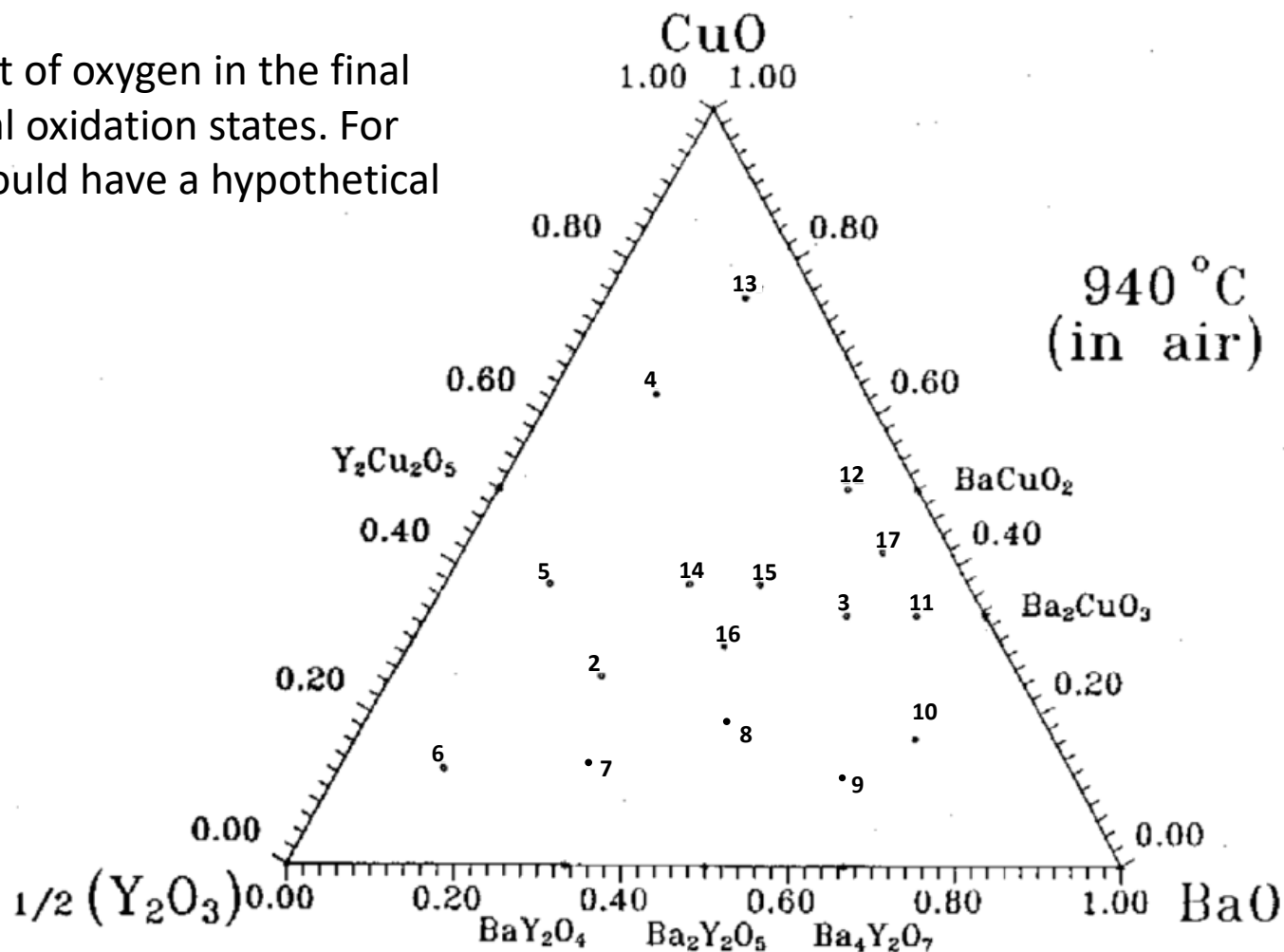
BaCO_3 – 197.34 g/mol

CuO – 79.545 g/mol

Y – 88.91 g/mol

Ba – 137.33 g/mol

Cu – 63.55 g/mol



Back to solid state methods

Molten Fluxes Technique

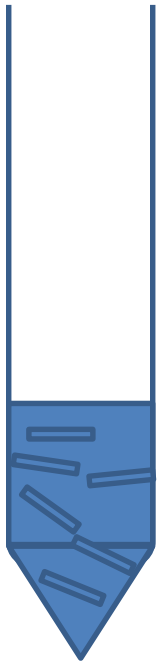
- Solubilize reactants → Enhanced Diffusion rate → Faster Reaction completion.
- Synthesis needs to be carried out at a temperature where the flux is a liquid.

Opportunity

- Lower Temperature than that of solid state reaction
- Growing single crystal
- New compounds
- Stabilization of the metastable compounds

Molten Slats Fluxes

- $4\text{SrCO}_3 + \text{Al}_2\text{O}_3 + \text{Ta}_2\text{O}_5 = \text{Sr}_2\text{AlTaO}_6$ (SrCl_2 flux, 900°C)
- Powder sample, wash away SrCl_2 with weakly acidic H_2O
- Direct synthesis requires $T > 1400^\circ\text{C}$ and $\text{Sr}_2\text{Ta}_2\text{O}_7$ impurities persist even at 1600°C

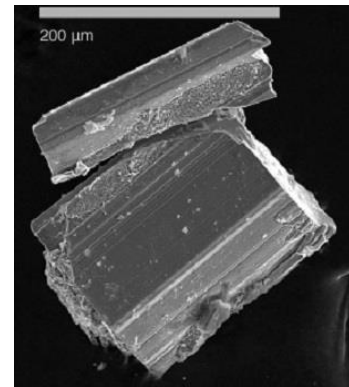
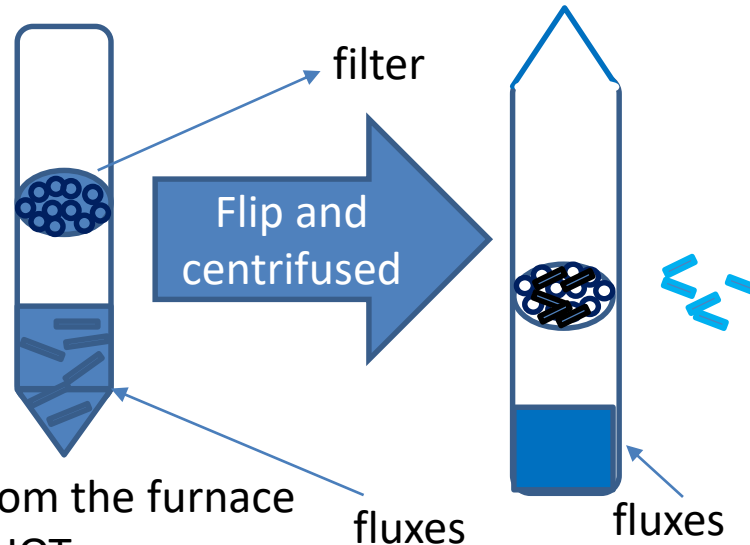


Metal Fluxes

- One of the reactants is metal
- Typical for intermetallic compounds
- Reaction products are unpredictable
- Great technique to obtain new compounds
- Flux metals with low melting and high boiling points; Typical metals are Ga, In, Pb, Sn, Sb, etc



Remove from the furnace
HOT

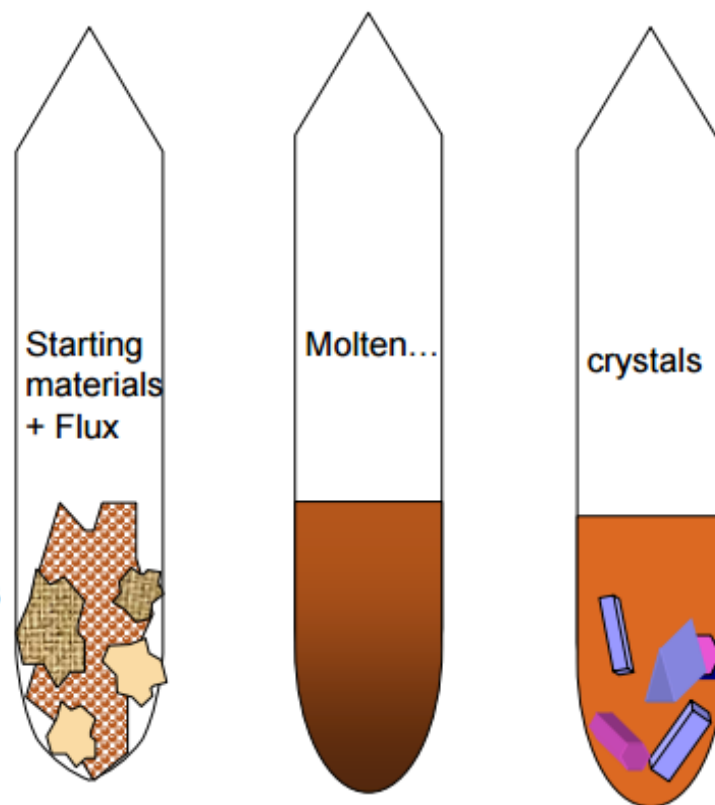


Polychalcogenides Fluxes

- Molten chalcogenide salts ($A_2Q + Q_x \rightarrow A_2Q_x$) as **Reagents and Solvents** to synthesize new compounds

ADVANTAGES

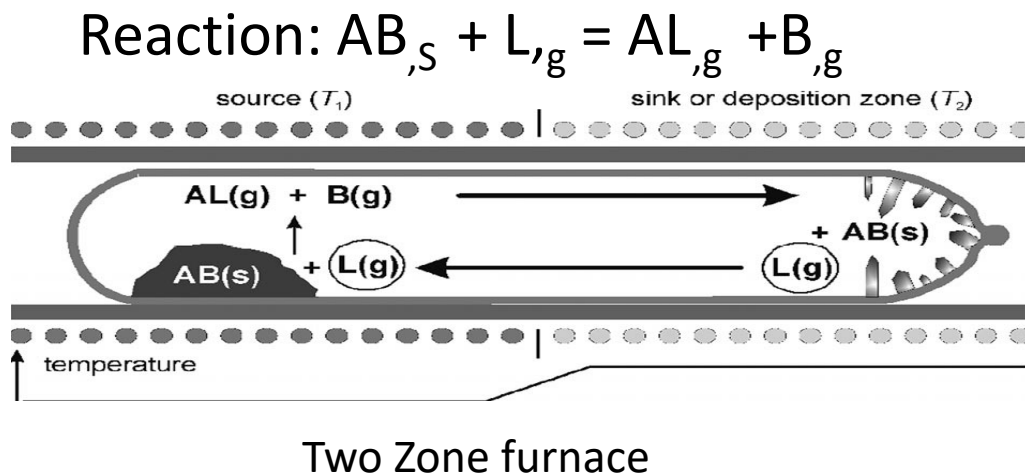
- Low temperatures ($250\text{ }^{\circ}\text{C} < T < 750\text{ }^{\circ}\text{C}$)
- Can produce compounds not accessible by other methods
 - Kinetic products / Thermodynamic products
- Conducive to large crystal growth
- Ability to produce in pure form more complicated compounds such as ternary: A/Bi/Q or quaternary: A/M/Bi/Q)



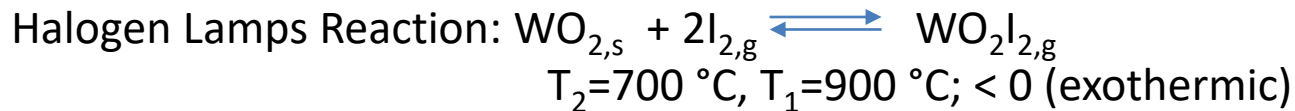
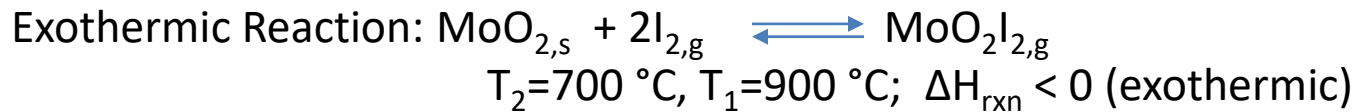
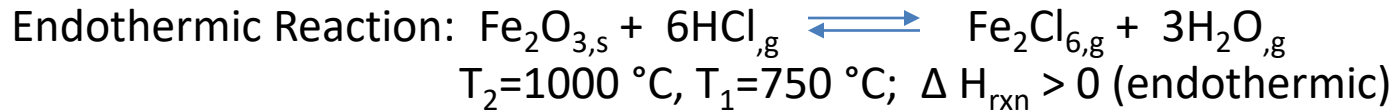
M. G. Kanatzidis and A. Sutorik *Progress in Inorganic Chemistry*
1995, 43, 151-265.

Chemical Vapor Transport (CVT)

- CVT is a heterogeneous catalysis process that produced crystals of the desired compounds by the condensation of the supersaturated gaseous substances.
- Bunsen, first described a naturally occurring vapor transport reaction in 1852.
- During the eruption of the volcano *Vesuv* Bunsen noticed the formation of hematite in the presence of hydrogen chloride.



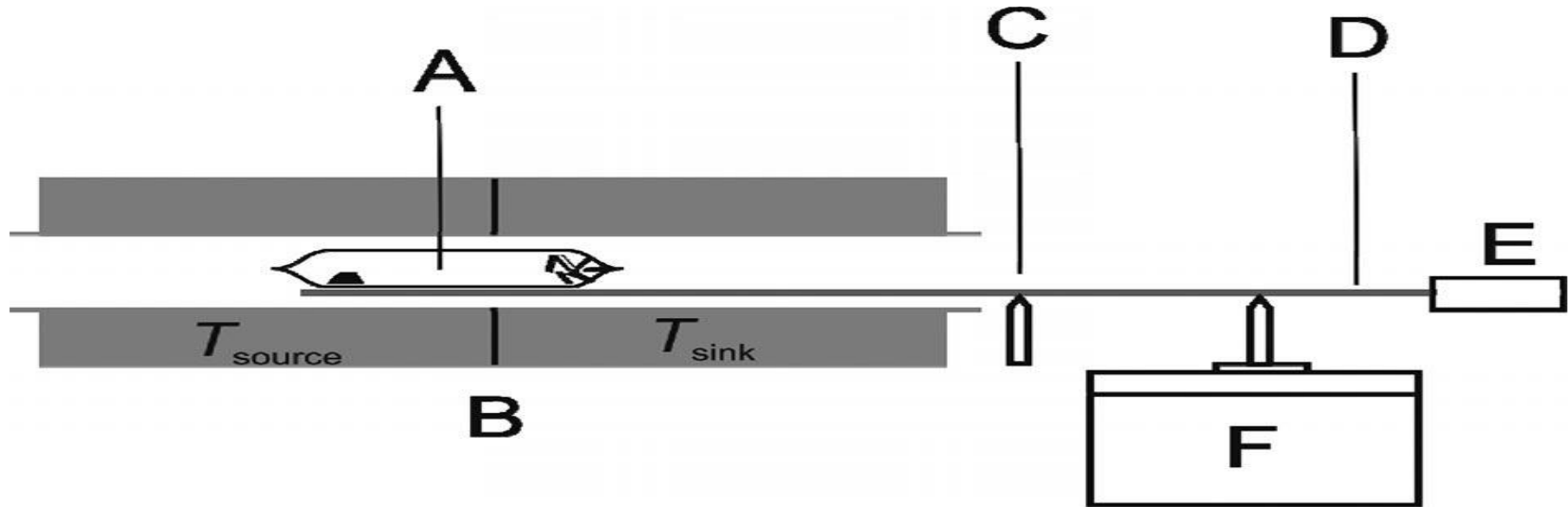
Chemical Vapor Transport



Tungsten is evaporated from the filament, converts to WO_2I_2 (g) with the traces of oxygen and iodine. At the high temperature near filament it decomposes back to W, O_2 and I_2 .



Chemical Vapor Transport



$$\dot{n}(A) = \frac{n(A)}{t'} = \frac{i}{j} \cdot \frac{\Delta p(C)}{\Sigma p} \cdot \frac{\bar{T}^{0.75} \cdot q}{s} \cdot 0.6 \cdot 10^{-4} \text{ (mol} \cdot \text{h}^{-1}\text{)}$$

$\dot{n}(A)$ = Transport rate (mol·h⁻¹)

i, j = Stoichiometric coefficients in the transport equation

$\Delta p(C)$ = Partial pressure difference of the transport effective species C (bar)

Σp = Total pressure (bar)

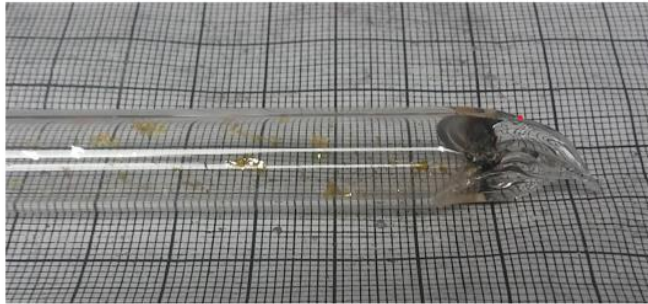
$\bar{T}$ = Mean temperature along the diffusion path (K) (practically $\bar{T}$ can be taken as average of T_1 and T_2)

q Cross section of the diffusion path (cm²)

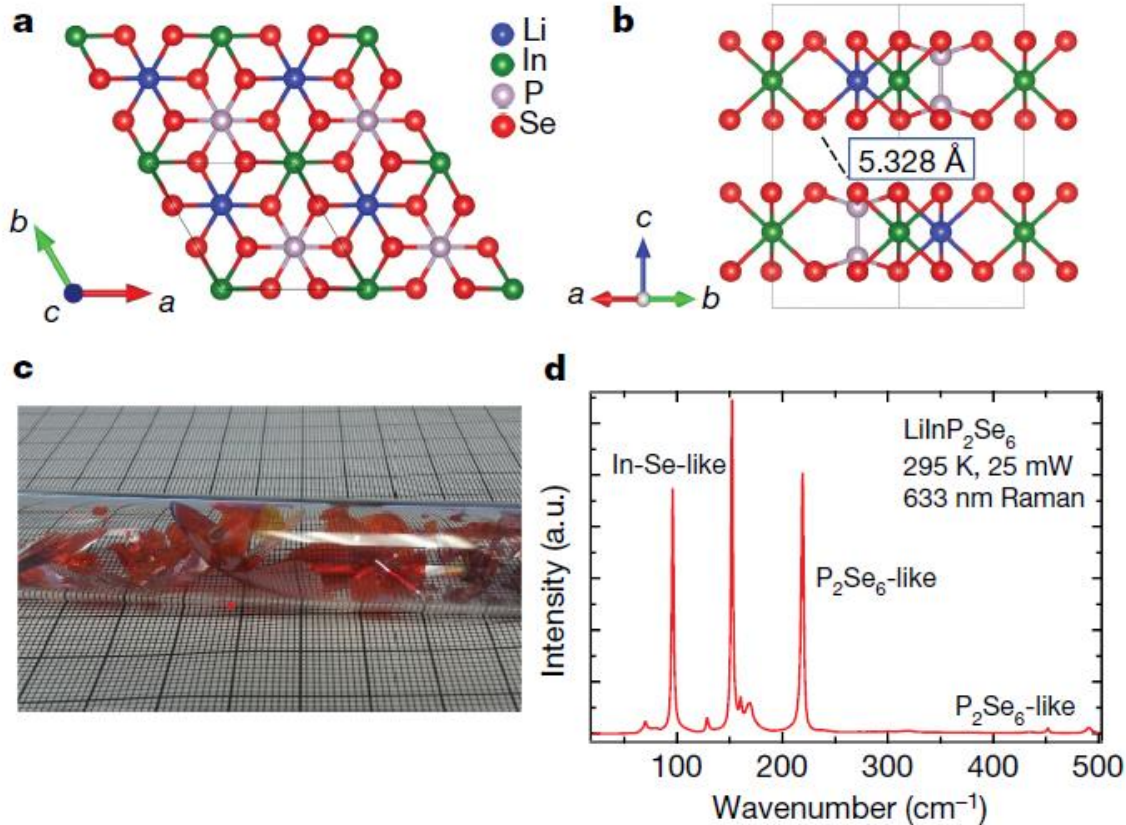
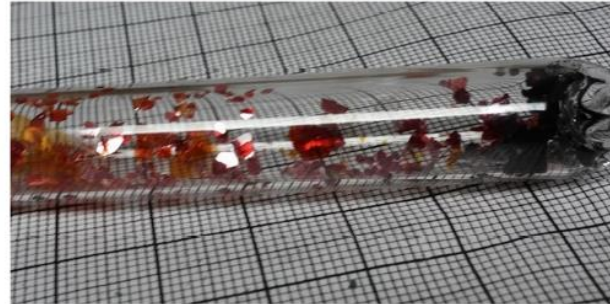
s Length of the diffusion path (cm)

t Duration of the transport experiments (h)

Chemical Vapor Transport –recent example



e



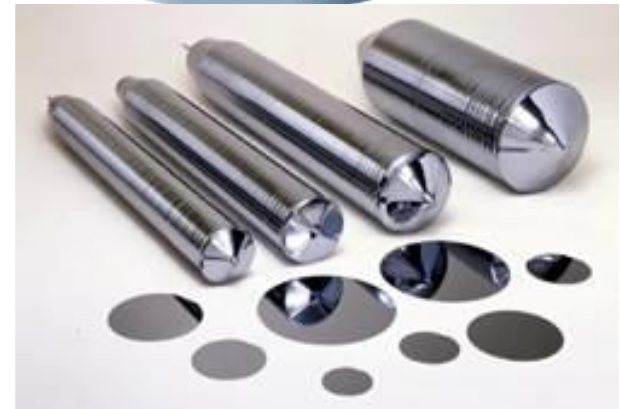
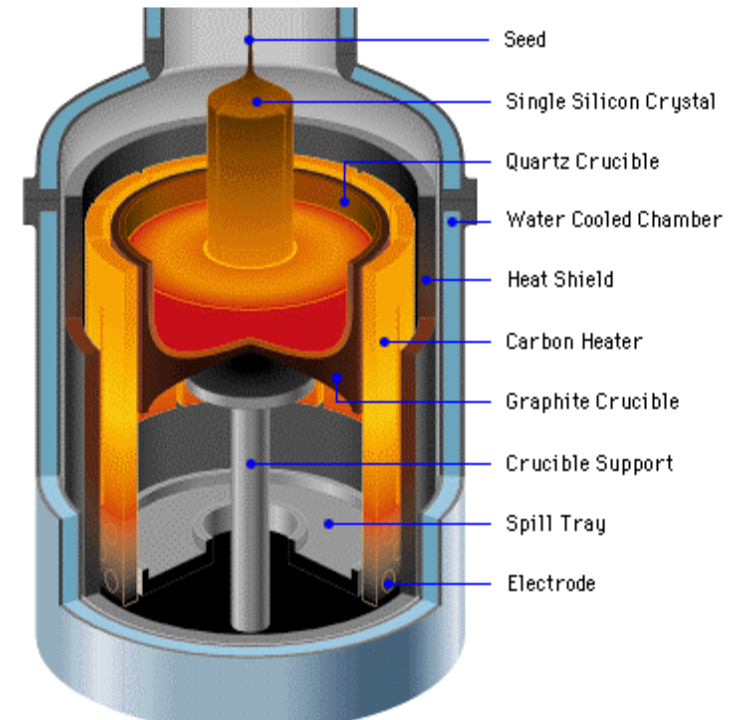
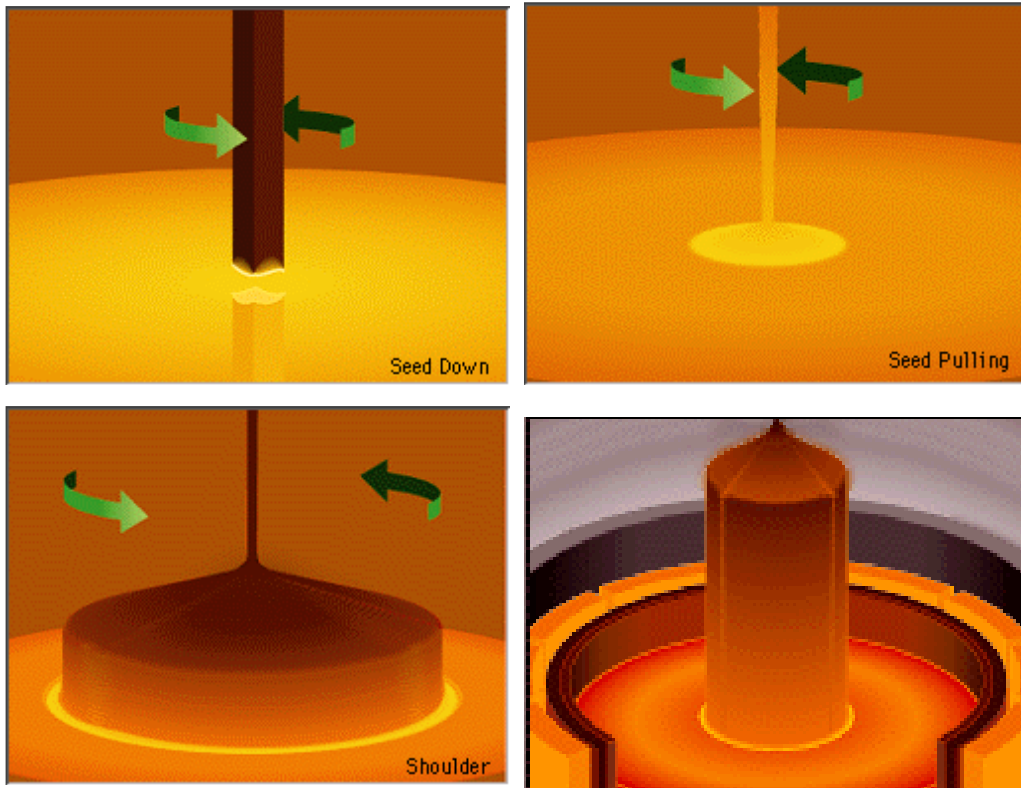
Czochralski process

Large single crystals are made by the Czochralski process.

- The silicon is melted in an atmosphere of Ar, then a single crystal seed rod is used as a seed which is dipped into the melt.
- The crystal is slowly withdrawn, pulling an ever lengthening single crystal in the same orientation as the original seed.

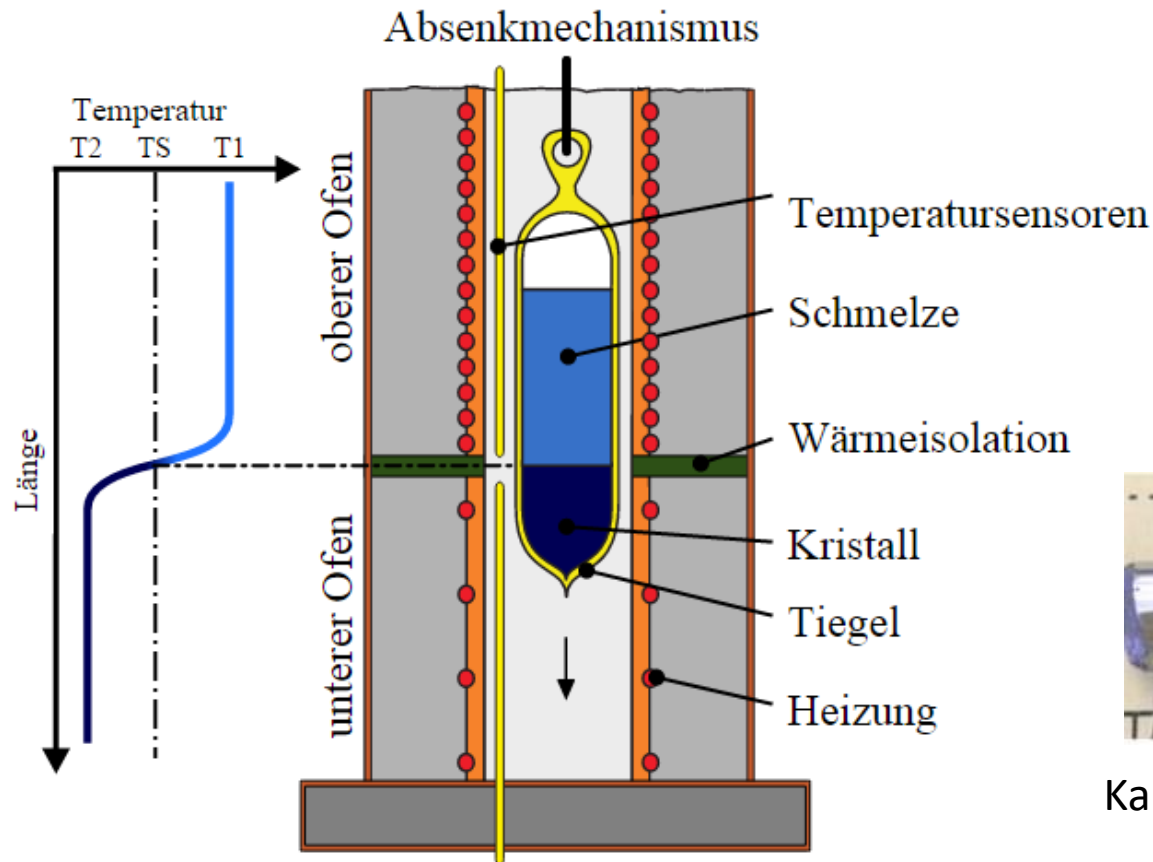
Czochralski process

Seed is brought to the contact of the melts
Slowly rotate and pull out from the solution



Bridgman Crystal growth

Crystallization from melts
High purity large crystals



Kanatzidis, et al. J. Am. Chem. Soc.
2011, 133, 10030



Kanatzidis, et al., *Nature*, **2014**, 508, 373

Bridgmann Crystal Growth

Crystal Growth

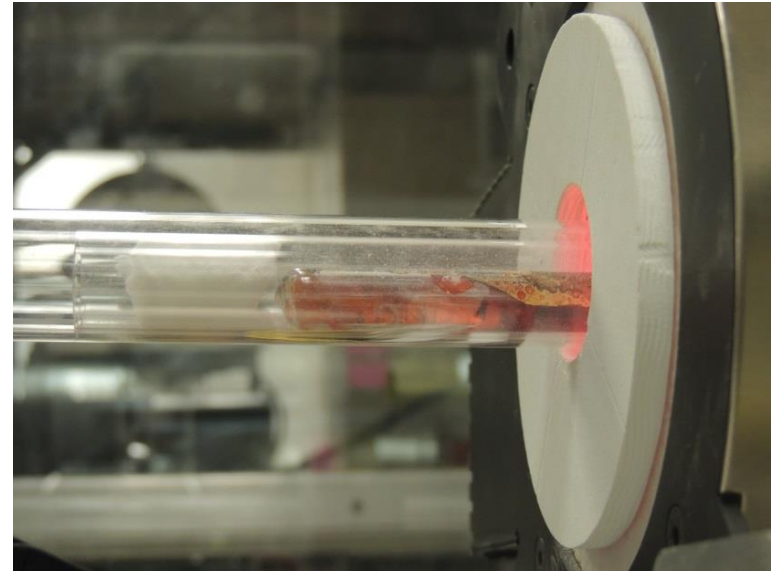
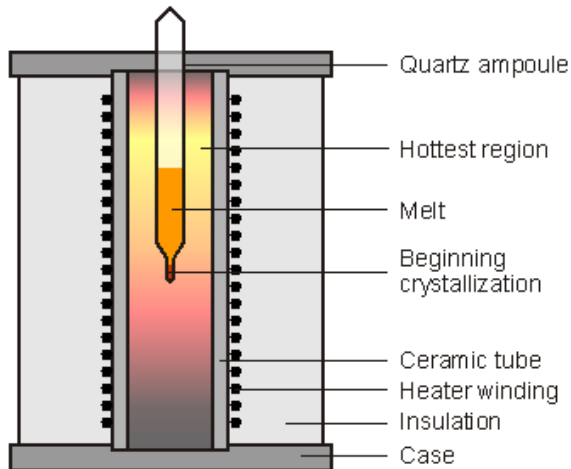
Single-Crystal Growth

- **Bridgman method**
- Growth from the melt
- Purification of raw materials
- **Zone refining**

Bridgman Furnace

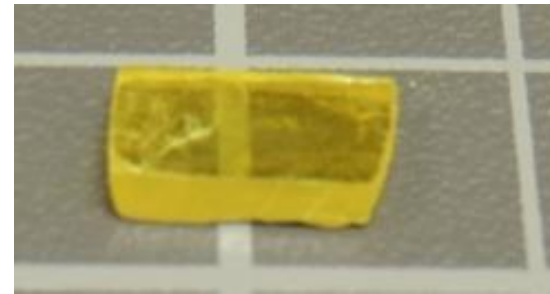
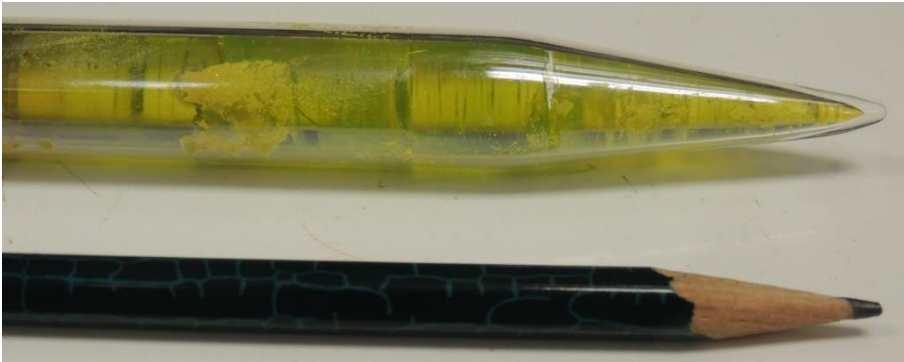
(Cross section)

Growing Crystals by the "Bridgman Technique"



Crystal Growth and Processing

$\text{Cs}_3\text{Bi}_2\text{Br}_9$



CsPbBr_3



$\text{Cs}_3\text{Bi}_2\text{I}_9$



Solution Combustion Synthesis (S)

- Combustion synthesis is a **self-propagating high temperature synthetic** method.
- CS uses highly exothermic ($\Delta H < -170$ kJ/mol) and even explosive reactions to maintain a self-propagating high reaction temperature.
- Reactants are mixed together, formed into a pellet, and ignited (laser, electric arc, heating coil) at high temperature.
- Once ignited, the reaction propagates as a synthesis wave, the reaction must lose less heat than it generates, or it will quench.
- Temperatures up to 3000 K are maintained during the fast reaction.

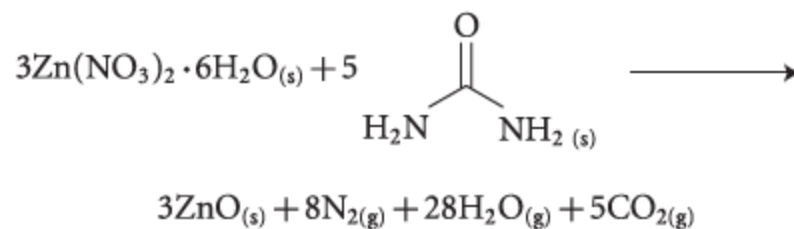
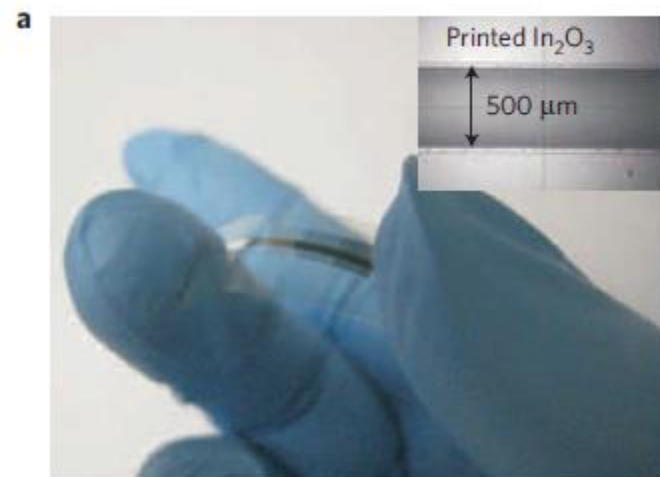
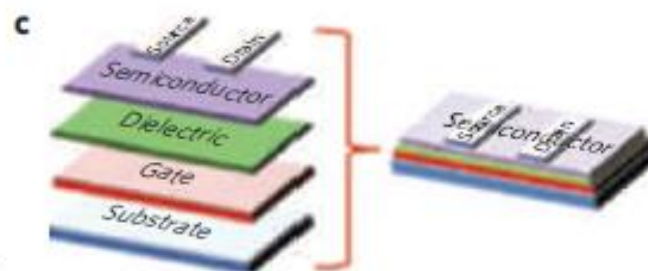
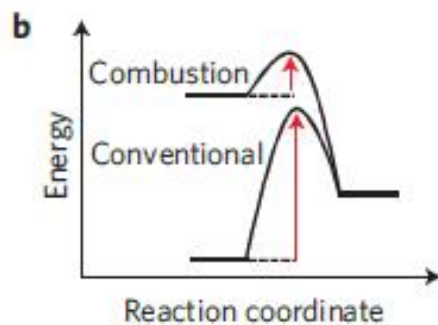
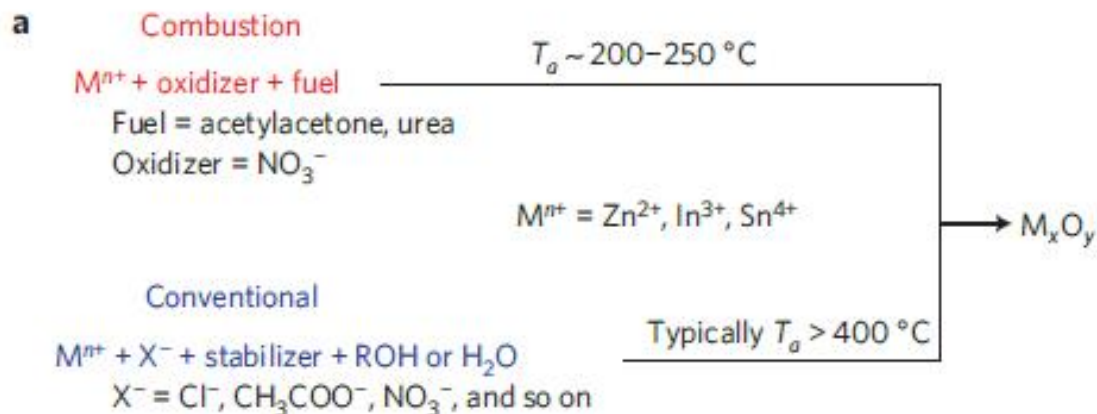
Reactants + Fuel $\rightarrow$ exothermic energy

Usually Nitrates

Organic compounds

Very short reaction time

Generation gaseous stuffs



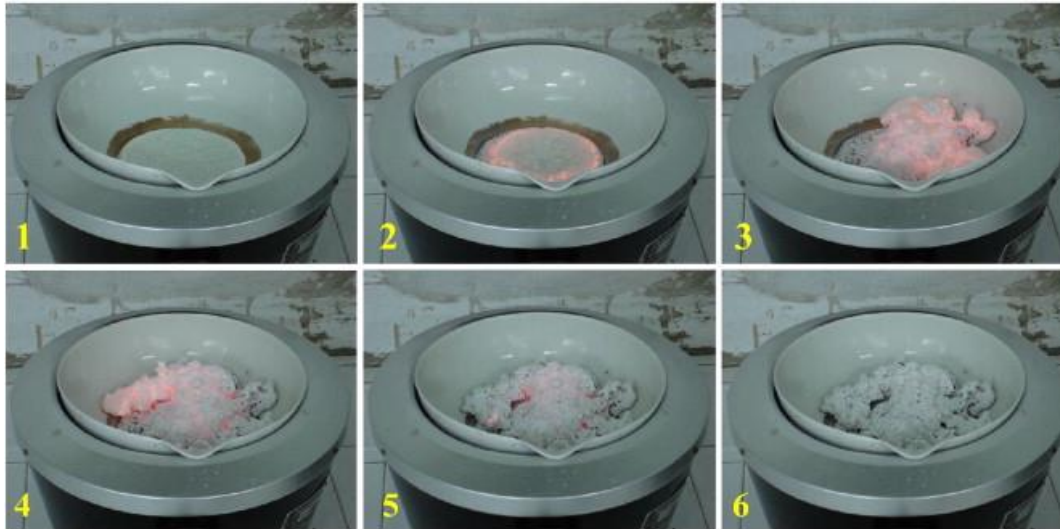
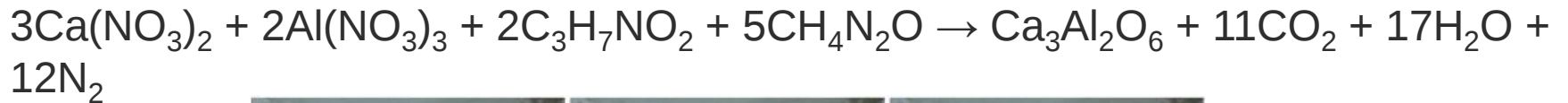
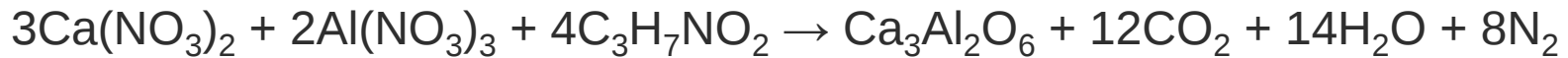
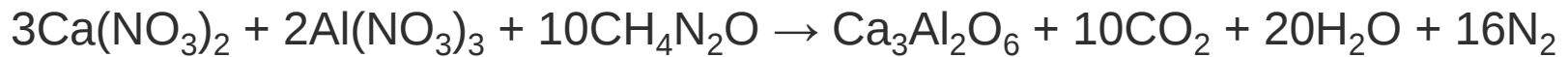
$$\Delta H_{298\text{ K}} = -2320.4\text{ kJ and } T_{\text{ad}} \sim 700\text{ }^\circ\text{C}$$

(1)

M.-K. Kim *Nat. Mater.* **2011** 10 382

Solution combustion

Synthesis of $\text{Ca}_3\text{Al}_2\text{O}_6$



Hydro(Solvo)thermal Synthesis

- Water as solvent or any solvent
- Temperatures close or above 100 °C
- Pressures above 1 bar
- Sealed vessels
- Dissolve otherwise insoluble materials
- Properties of water/solvent change

Properties of water

- Viscosity – lowered to 10% of value in normal conditions at 100 bar and 500 °C
 - Increase mobility
- Autoionization
 - $\text{pK}_w = 7.85 \pm 0.3$ at 1000 °C and 10 kbar

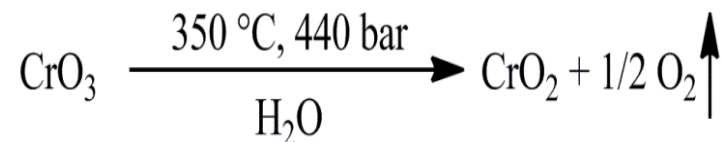
Seward, T.M. *Phys. Chem. Earth*. **1981**, 13-14, 113.

Rabenau, A. *Angew. Chem. Int. Ed. Engl.* **1985**, 24, 1026.

Hamann, S.D. *Phys. Chem. Earth*. **1981**, 13-14, 89.

Opportunity

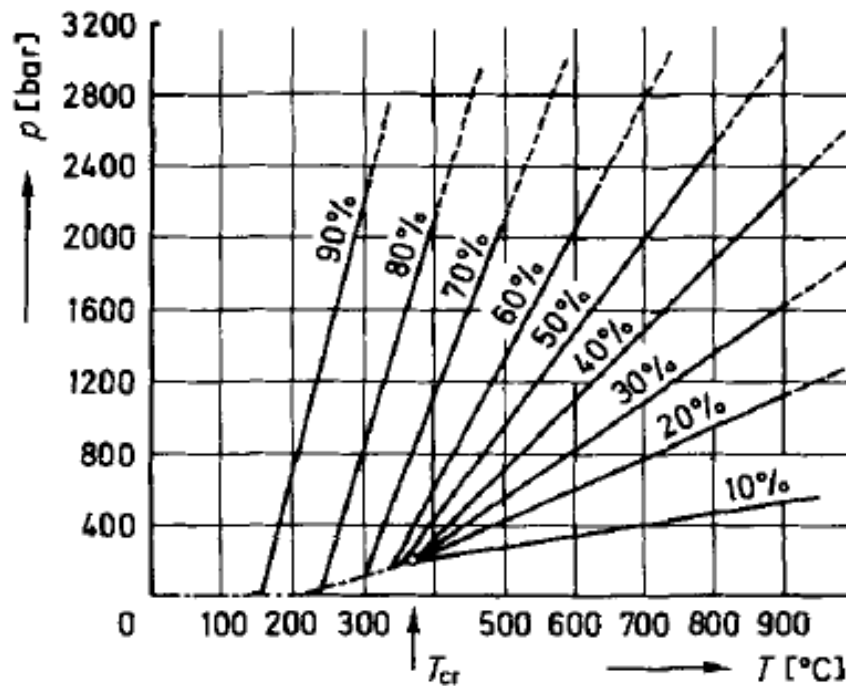
- To grow crystal with unusual oxidation states



- Produce low temperature phases
 - γ -phase of CuI (390 °C) – p-type semiconductor
- Isolate metastable phases
 - h-MoO₃
- Low temperature synthesis
- Synthesis of nano crystal to large single crystals,
- High purity single crystal
- Accessible compounds which other techniques does not permit such as certain MOF and Zeolites

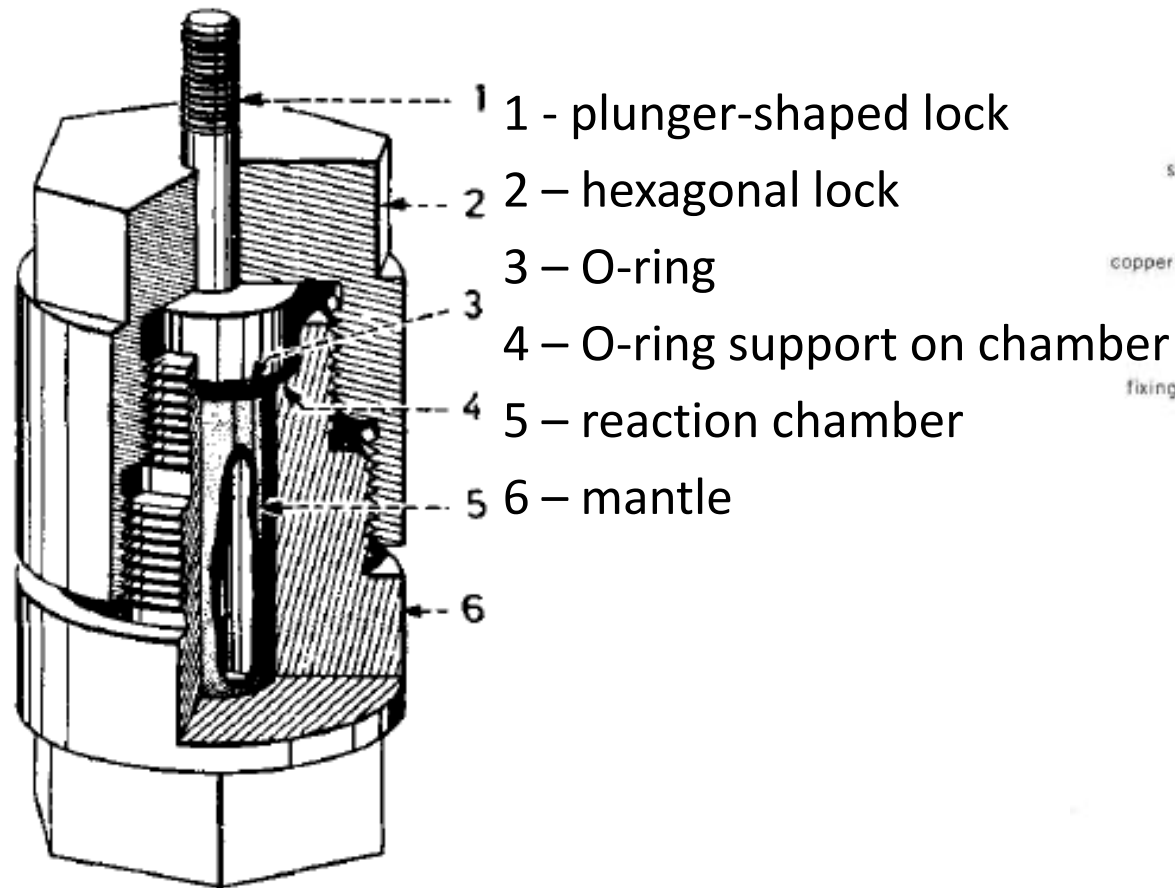
Autogenous Pressure

- Closed systems (reaction vessel is closed)
- Pressure is self-produced
- Increases boiling point of water



Pressure-Temperature diagram of water

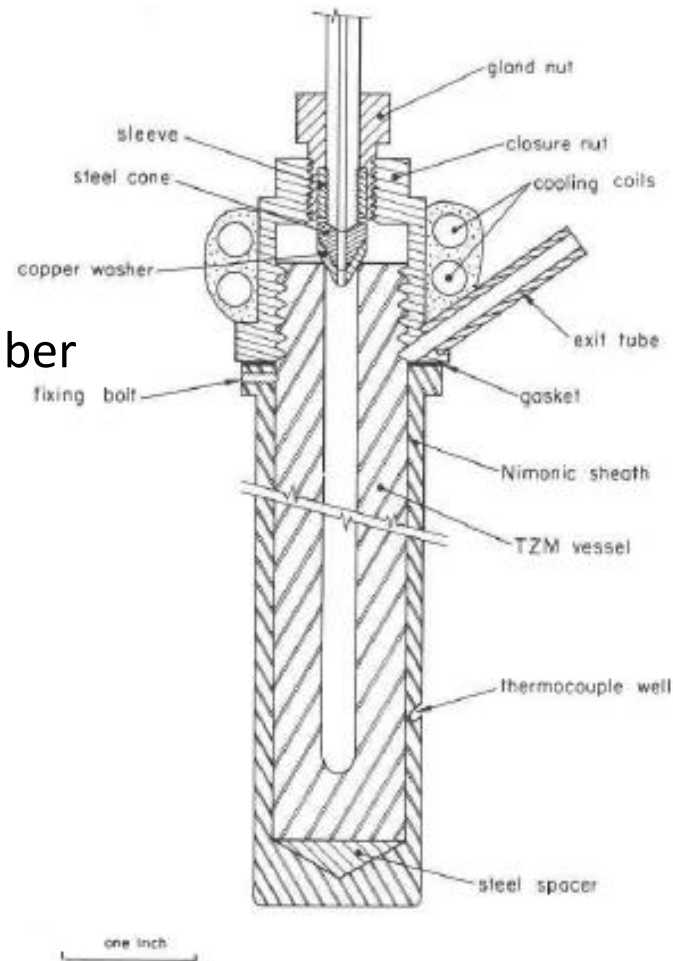
Autoclaves



400 °C and 400 bar

Morey, G.W. *J. Am. Chem. Soc.* **1914**, 36, 215.

Rabenau, A. *Angew. Chem. Int. Ed. Engl.* **1985**, 24, 1026.



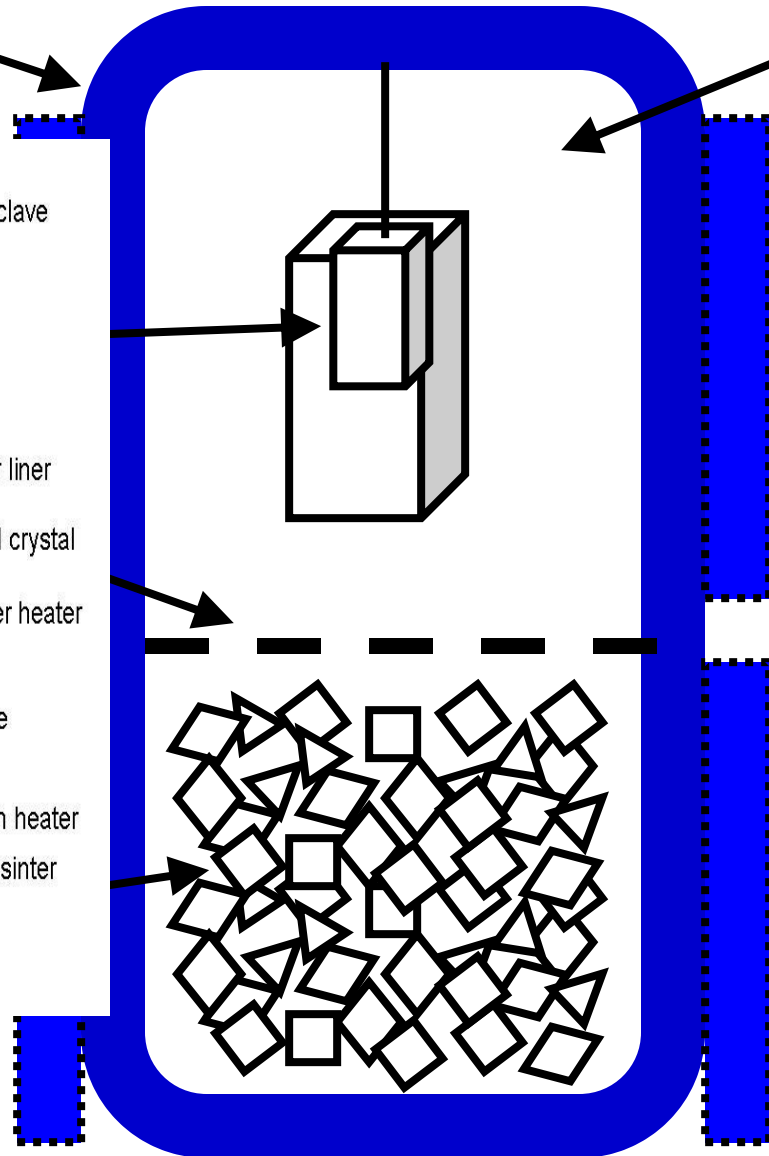
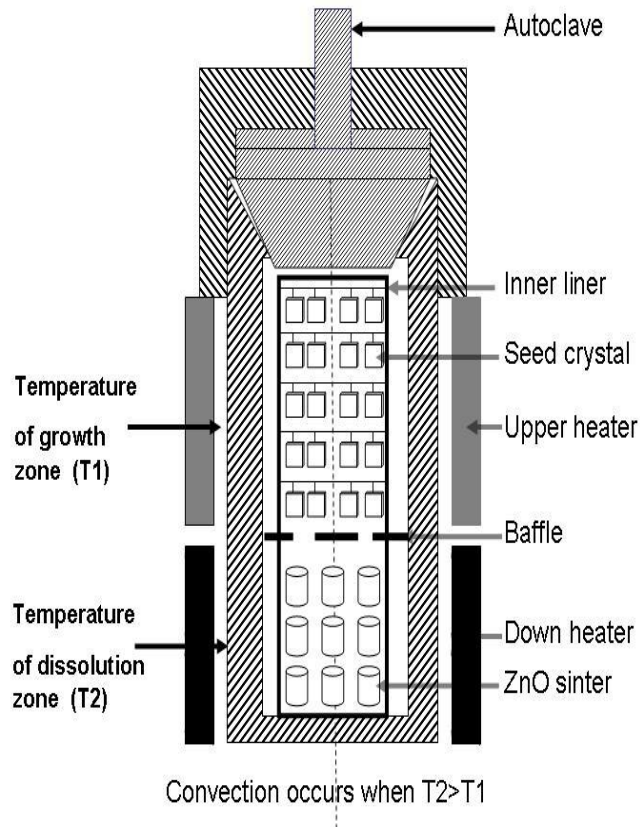
1100 °C and 3 kbar

Externally regulated pressure

Hydrothermal Growth: Methods and Instrument

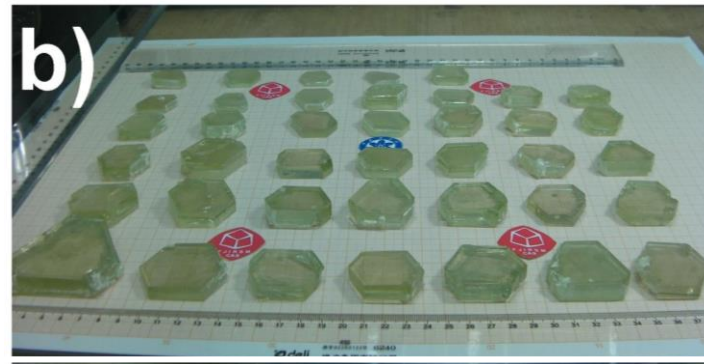
High pressure
Autoclave

Mineralizer
Solution

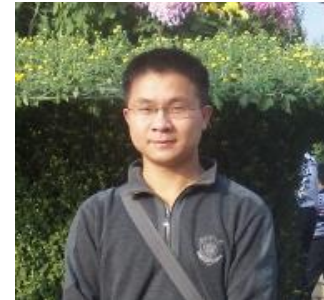
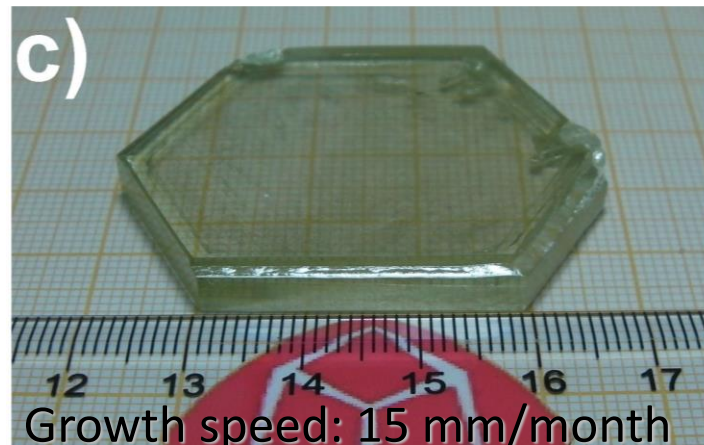


Mass Production of Inches Sized ZnO by a Low-cost Hydrothermal Method

Homemade autoclave. It can accommodates 100 1' sized or 36 2' sized seed wafers.



One third of crystals grown in one autoclave after 14 days' growth.



Dr. Wenwen Lin

T2=350C

T1=300C

P=1000 bar

Industrial Growth

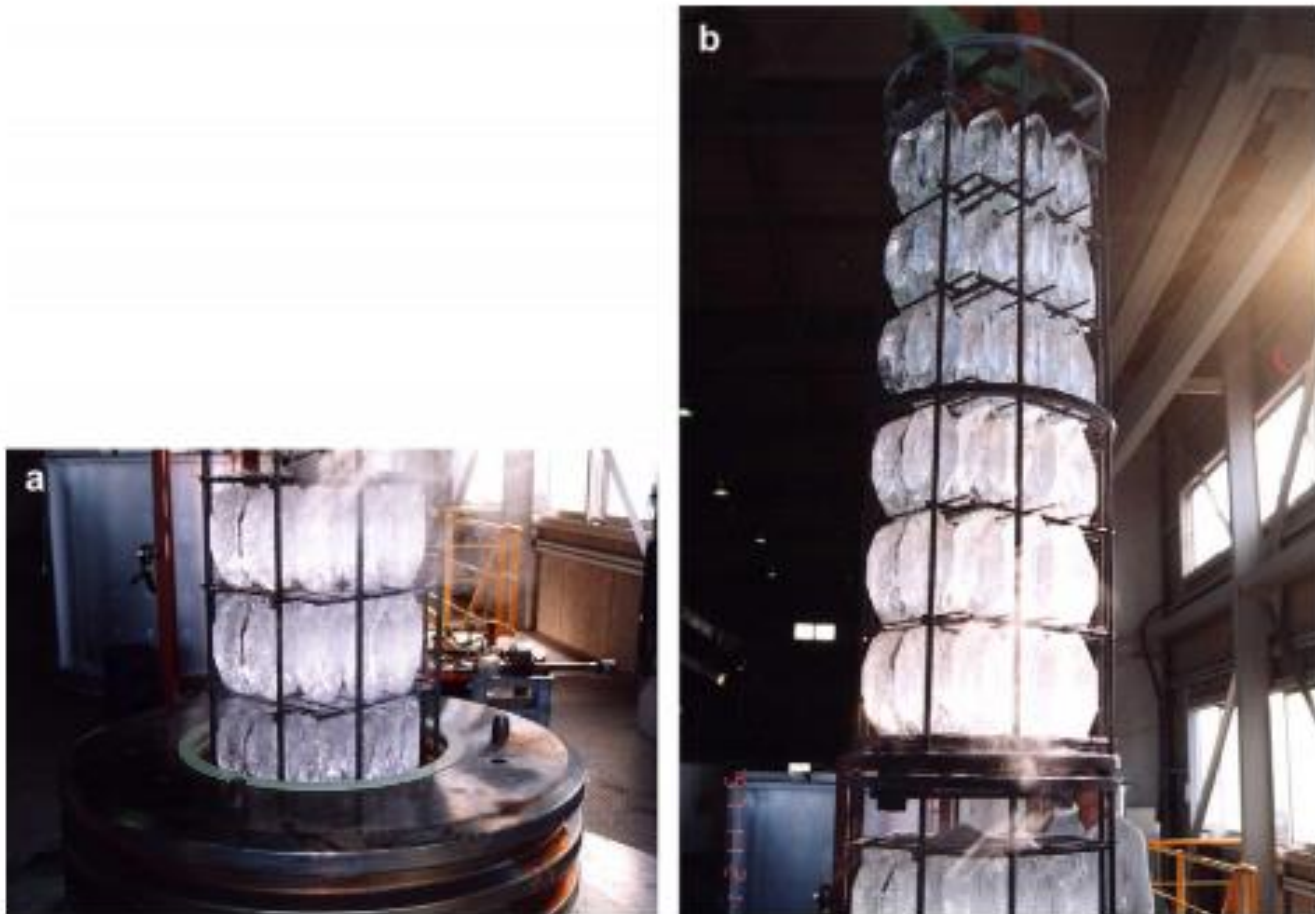
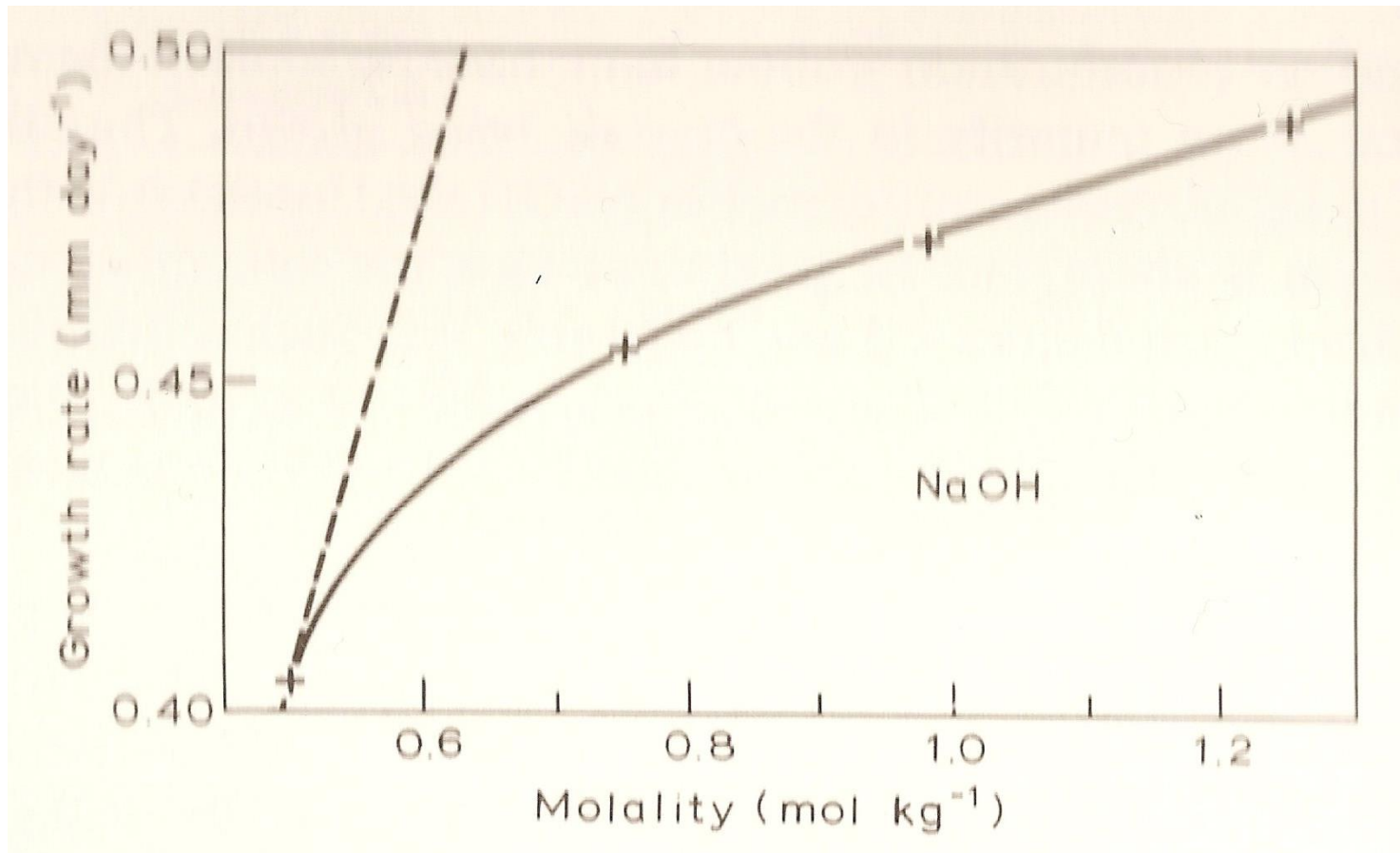


Fig. 2. (a) Quartz crystals being withdrawn from the autoclave of 0.65 m inner diameter and 14 m length; (b) crystal holder with about 25 cm large quartz crystals.

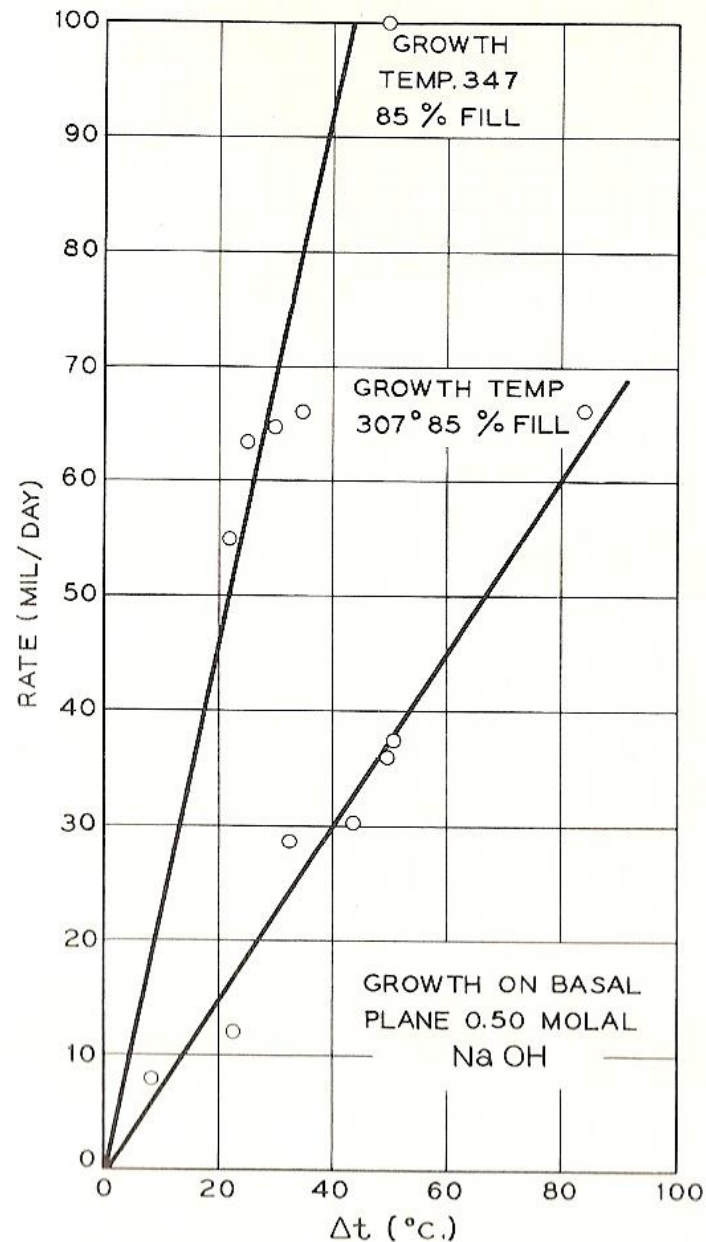
Growth Rate Variables

- Concentration of the mineralizer
- Degree fill of the vessel
- Crystallization temperature
- Temperature difference between the nutrient and growth zones

Mineralizer Concentration



Temperature Gradient



Laudise, R.A. Hydrothermal Growth. In *Crystal Growth: an introduction*; Hartman, P., Ed.; North-Holland Publishing Company: Amsterdam, 1973

Hydrothermal Timeline

